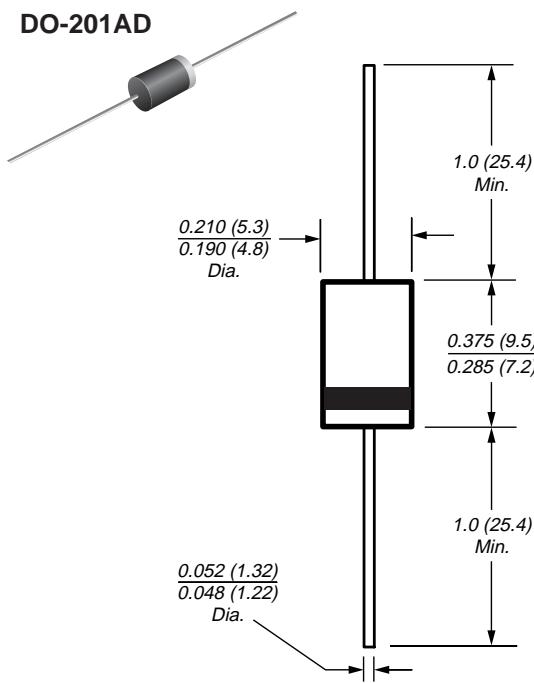


General Purpose Rectifiers

DO-201AD

Dimensions in inches and (millimeters)

Maximum Ratings & Thermal Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Parameter	Symbol	BY251P	BY252P	BY253P	BY254P	BY255P	Unit
Maximum repetitive peak reverse voltage	V _{RRM}	200	400	600	800	1300	V
Maximum RMS voltage	V _{RMS}	140	280	420	560	910	V
Maximum DC blocking voltage	V _{DC}	200	400	600	800	1300	V
Maximum average forward rectified current 10mm lead length at TA = 55 °C	I _{F(AV)}				3.0		A
Peak forward surge current 10ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}				150		A
Maximum full load reverse current, full cycle average 10mm lead length at TA = 55 °C	I _{R(AV)}			100			µA
Typical thermal resistance ⁽¹⁾	R _{θJA} R _{θJL}			20 10			°C/W
Operating junction and storage temperature range	T _J , T _{STG}			-65 to +150			°C

Electrical Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Maximum instantaneous forward voltage at 3.0A	V _F	1.1	V
Maximum reverse current at rated DC blocking voltage TA = 25°C	I _R	5.0	µA
Typical reverse recovery time I _F = 0.5A, I _R = 1.0V, I _{rr} = 0.25A	t _{rr}	3.0	µs
Typical junction capacitance at 4.0V, 1MHz	C _J	40	pF

Note: (1) Thermal resistance from junction to ambient and from junction to lead at 0.375" (9.5mm) lead length, P.C.B. mounted

BY251P thru BY255P

Vishay Semiconductors
formerly General Semiconductor



Ratings and Characteristic Curves ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig 1 - Forward Current Derating Curve

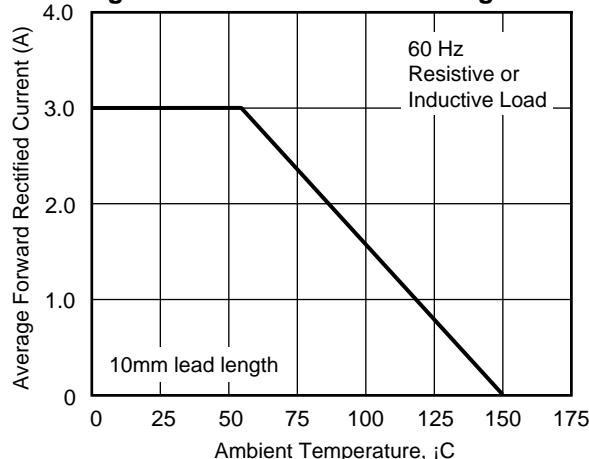


Fig 2 - Maximum Non-repetitive Peak Forward Surge Current

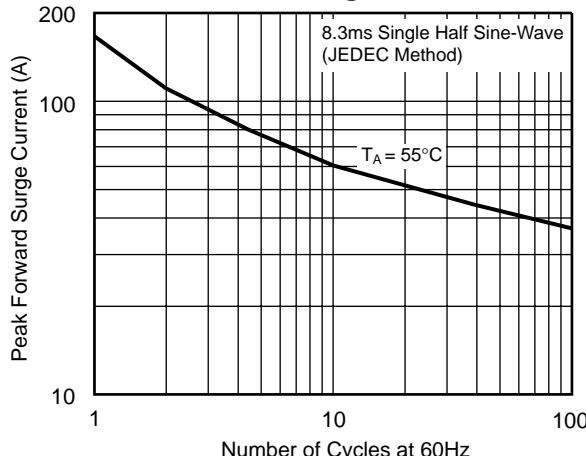


Fig 3 - Typical Instantaneous Forward Characteristics

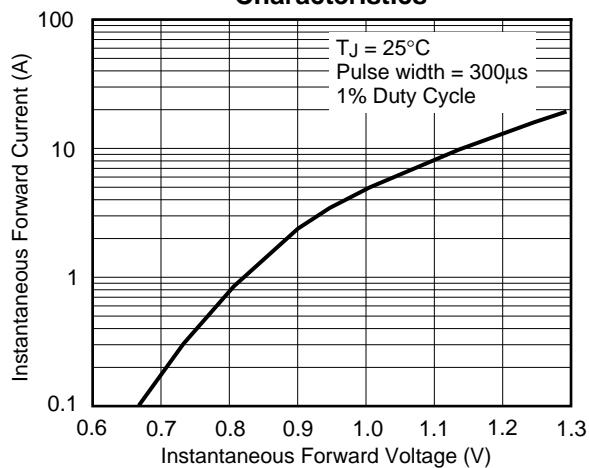


Fig 2 - Maximum Non-repetitive Peak Forward Surge Current

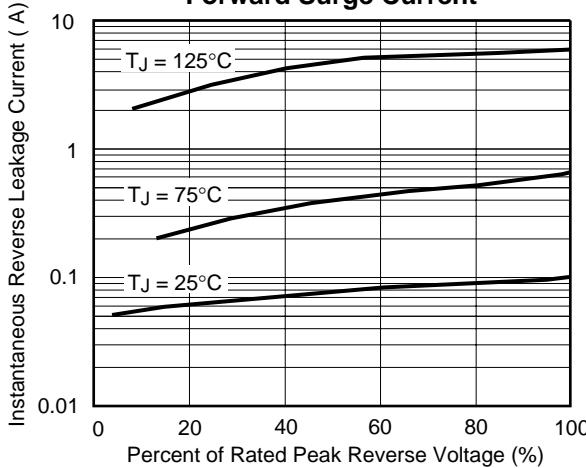


Fig 5 - Typical Junction Capacitance

